

isc Silicon NPN Darlington Power Transistor

2SD2493

DESCRIPTION

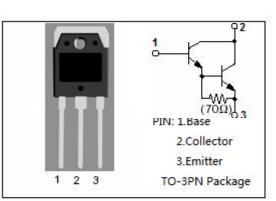
- Collector-Emitter Breakdown Voltage-: V_{(BR)CEO}= 110V(Min)
- High DC Current Gain-
- : h_{FE} = 5000(Min.) @(I_C= 5A, V_{CE}= 4V)
- Low Collector Saturation Voltage-
- : $V_{CE(sat)}$ 2.5V(Max)@ (I_C= 5A, I_B= 5mA)
- Complement to Type 2SB1624
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

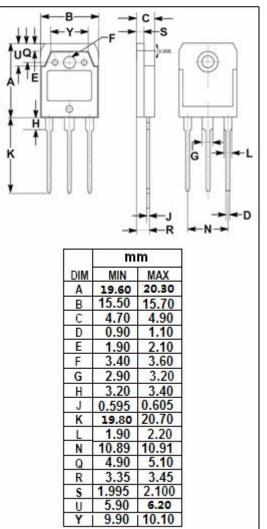
APPLICATIONS

 Designed for audio, series regulator and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	110	V
V _{CEO}	Collector-Emitter Voltage	110	V
V _{EBO}	Emitter-Base Voltage	5	V
lc	Collector Current-Continuous	6	А
I _B	Base Current-Continuous	1	А
Pc	Collector Power Dissipation @T _C =25℃	60	W
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~150	°C







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ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 30mA ; I _B = 0	110			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 5mA			2.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	Ic= 5A; I _B = 5mA			3.0	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 110V; I _E = 0			100	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			100	μA
h _{FE}	DC Current Gain	I _C = 5A; V _{CE} = 4V	5000			
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1MHz		55		pF
f⊤	Current-Gain—Bandwidth Product	I _E = -2A ; V _{CE} = 12V		60		MHz

Switching Times

ton	Turn-on Time		0.8	μS
tstg	Storage Time	V _{CC} = 30V, RL= 6 Ω , I _C = 5A; I _{B1} = -I _{B2} = 5mA,	6.2	μs
tf	Fall Time		1.1	μs

h_{FE} Classifications

0	Р	Y
5000-12000	6500-20000	15000-30000

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